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FGH40T65UPD

650 V, 40 A Field Stop Trench IGBT

Features

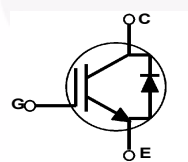
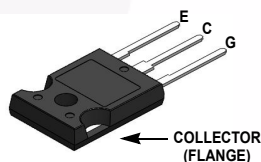
- Maximum Junction Temperature : $T_J = 175^{\circ}\text{C}$
- Positive Temperature Co-efficient for Easy Parallel Operating
- High Current Capability
- Low Saturation Voltage: $V_{CE(sat)} = 1.65 \text{ V(Typ.)} @ I_C = 40 \text{ A}$
- 100% of Parts Tested $I_{LM(2)}$
- High Input Impedance
- Tightened Parameter Distribution
- RoHS Compliant
- Short Circuit Ruggedness $> 5 \text{ us} @ 25^{\circ}\text{C}$

General Description

Using innovative field stop trench IGBT technology, Fairchild's new series of field-stop trench IGBTs offer optimum performance for solar inverter, UPS, welder, and digital power generator where low conduction and switching losses are essential.

Applications

- Solar Inverter, UPS, Welder, Digital Power Generator
- Telecom, ESS



Absolute Maximum Ratings

| Symbol | Description | Ratings | Unit |
|-------------|---|-------------|--------------------|
| V_{CES} | Collector to Emitter Voltage | 650 | V |
| V_{GES} | Gate to Emitter Voltage | ± 20 | V |
| | Transient Gate to Emitter Voltage | ± 25 | V |
| I_C | Collector Current @ $T_C = 25^{\circ}\text{C}$ | 80 | A |
| | Collector Current @ $T_C = 100^{\circ}\text{C}$ | 40 | A |
| $I_{CM(1)}$ | Pulsed Collector Current | 120 | A |
| $I_{LM(2)}$ | Clamped Inductive Load Current @ $T_C = 25^{\circ}\text{C}$ | 120 | A |
| I_F | Diode Forward Current @ $T_C = 25^{\circ}\text{C}$ | 40 | A |
| | Diode Forward Current @ $T_C = 100^{\circ}\text{C}$ | 20 | A |
| $I_{FM(1)}$ | Pulsed Diode Maximum Forward Current | 120 | A |
| P_D | Maximum Power Dissipation @ $T_C = 25^{\circ}\text{C}$ | 268 | W |
| | Maximum Power Dissipation @ $T_C = 100^{\circ}\text{C}$ | 134 | W |
| SCWT | Short Circuit Withstand Time @ $T_C = 25^{\circ}\text{C}$ | 5 | us |
| T_J | Operating Junction Temperature | -55 to +175 | $^{\circ}\text{C}$ |
| T_{stg} | Storage Temperature Range | -55 to +175 | $^{\circ}\text{C}$ |
| T_L | Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds | 300 | $^{\circ}\text{C}$ |

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

2: $I_C = 120 \text{ A}$, $V_{CE} = 400 \text{ V}$, $R_g = 15 \Omega$

Thermal Characteristics

| Symbol | Parameter | Typ. | Max. | Unit |
|-------------------------------|---|------|------|----------------------|
| $R_{\theta JC}(\text{IGBT})$ | Thermal Resistance, Junction to Case | - | 0.56 | $^{\circ}\text{C/W}$ |
| $R_{\theta JC}(\text{Diode})$ | Thermal Resistance, Junction to Case | - | 1.71 | $^{\circ}\text{C/W}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | - | 40 | $^{\circ}\text{C/W}$ |

Package Marking and Ordering Information

| Part Number | Top Mark | Package | Packing Method | Reel Size | Tape Width | Quantity |
|-------------|-------------|------------|----------------|-----------|------------|----------|
| FGH40T65UPD | FGH40T65UPD | TO-247 A03 | Tube | N/A | N/A | 30 |

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|--------------------------------------|--|--|------|------|------|------|
| Off Characteristics | | | | | | |
| BV _{CES} | Collector to Emitter Breakdown Voltage | V _{GE} = 0 V, I _C = 1 mA | 650 | - | - | V |
| $\frac{\Delta BV_{CES}}{\Delta T_J}$ | Temperature Coefficient of Breakdown Voltage | V _{GE} = 0 V, I _C = 250 uA | - | 0.65 | - | V/°C |
| I _{CES} | Collector Cut-Off Current | V _{CE} = V _{CES} , V _{GE} = 0 V | - | - | 250 | μA |
| I _{GES} | G-E Leakage Current | V _{GE} = V _{GES} , V _{CE} = 0 V | - | - | ±400 | nA |
| On Characteristics | | | | | | |
| V _{GE(th)} | G-E Threshold Voltage | I _C = 40 mA, V _{CE} = V _{GE} | 4.0 | 6.0 | 7.5 | V |
| V _{CE(sat)} | Collector to Emitter Saturation Voltage | I _C = 40 A, V _{GE} = 15 V | - | 1.65 | 2.3 | V |
| | | I _C = 40 A, V _{GE} = 15 V, T _C = 175°C | - | 2.1 | - | V |
| Dynamic Characteristics | | | | | | |
| C _{ies} | Input Capacitance | V _{CE} = 30 V, V _{GE} = 0 V, f = 1 MHz | - | 2730 | 3630 | pF |
| C _{oes} | Output Capacitance | | - | 82 | 110 | pF |
| C _{res} | Reverse Transfer Capacitance | | - | 48 | 72 | pF |
| Switching Characteristics | | | | | | |
| t _{d(on)} | Turn-On Delay Time | V _{CC} = 400 V, I _C = 40 A, R _G = 7 Ω, V _{GE} = 15 V, Inductive Load, T _C = 25°C | - | 20 | 26 | ns |
| t _r | Rise Time | | - | 26 | 34 | ns |
| t _{d(off)} | Turn-Off Delay Time | | - | 144 | 187 | ns |
| t _f | Fall Time | | - | 17 | 22 | ns |
| E _{on} | Turn-On Switching Loss | | - | 1.59 | 2.1 | mJ |
| E _{off} | Turn-Off Switching Loss | | - | 0.58 | 0.76 | mJ |
| E _{ts} | Total Switching Loss | V _{CC} = 400 V, I _C = 40 A, R _G = 7 Ω, V _{GE} = 15 V, Inductive Load, T _C = 175°C | - | 2.17 | 2.86 | mJ |
| t _{d(on)} | Turn-On Delay Time | | - | 19 | - | ns |
| t _r | Rise Time | | - | 38 | - | ns |
| t _{d(off)} | Turn-Off Delay Time | | - | 153 | - | ns |
| t _f | Fall Time | | - | 60 | - | ns |
| E _{on} | Turn-On Switching Loss | | - | 1.84 | - | mJ |
| E _{off} | Turn-Off Switching Loss | | - | 0.98 | - | mJ |
| E _{ts} | Total Switching Loss | | - | 2.82 | - | mJ |
| T _{SC} | Short Circuit Withstand Time | V _{GE} = 15 V, V _{CC} =400 V, R _G = 10 Ω | 5 | - | - | us |
| Q _g | Total Gate Charge | V _{CE} = 400 V, I _C = 40 A, V _{GE} = 15 V | - | 177 | 265 | nC |
| Q _{ge} | Gate to Emitter Charge | | - | 23 | 35 | nC |
| Q _{gc} | Gate to Collector Charge | | - | 100 | 150 | nC |

Electrical Characteristics of the Diode $T_C = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Test Conditions | | Min. | Typ. | Max | Unit |
|------------------|-------------------------------|---|------------------------|------|------|-----|------|
| V _{FM} | Diode Forward Voltage | I _F = 20 A | T _C = 25°C | - | 2.1 | 2.7 | V |
| | | | T _C = 175°C | - | 1.9 | - | |
| E _{rec} | Reverse Recovery Energy | I _F = 20 A, di _F /dt = 200 A/μs | T _C = 175°C | - | 96 | - | uJ |
| t _{rr} | Diode Reverse Recovery Time | | T _C = 25°C | - | 33 | 43 | ns |
| | | | T _C = 175°C | - | 128 | - | |
| Q _{rr} | Diode Reverse Recovery Charge | | T _C = 25°C | - | 53 | 74 | nC |
| | | | T _C = 175°C | - | 341 | - | |

Typical Performance Characteristics

Figure 1. Typical Output Characteristics

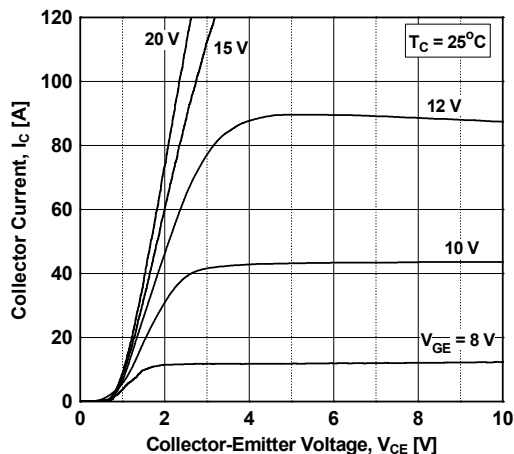


Figure 2. Typical Output Characteristics

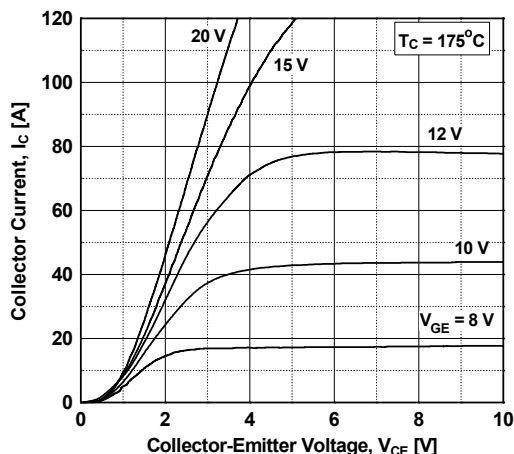


Figure 3. Typical Saturation Voltage Characteristics

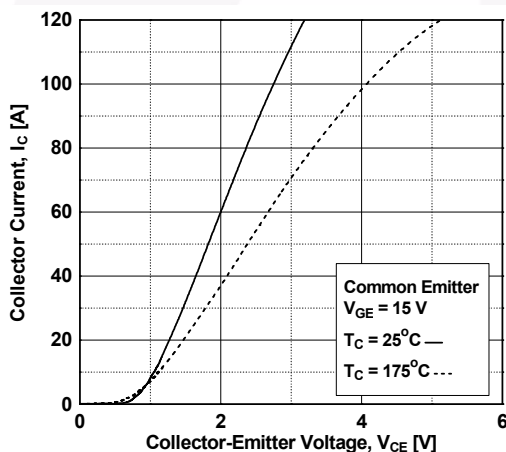


Figure 4. Saturation Voltage vs. Case Temperature at Variant Current Level

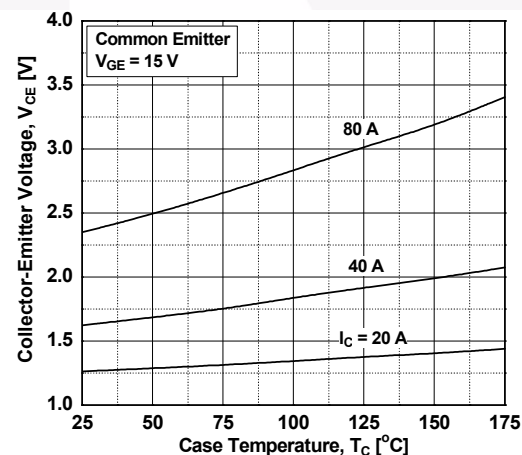


Figure 5. Saturation Voltage vs. V_{GE}

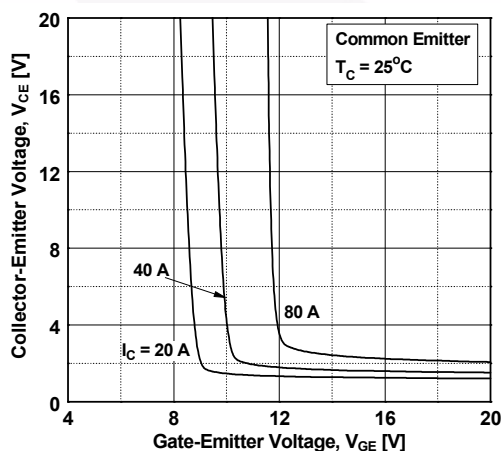
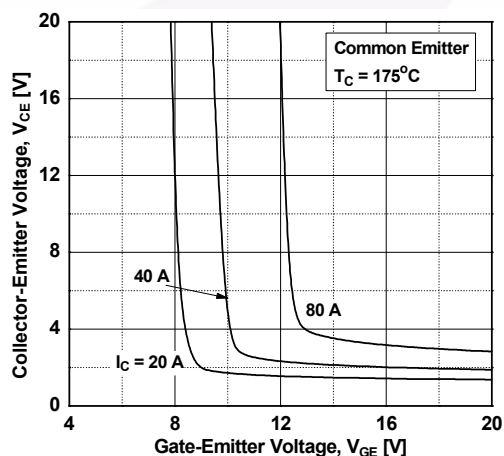


Figure 6. Saturation Voltage vs. V_{GE}



Typical Performance Characteristics

Figure 7. Capacitance Characteristics

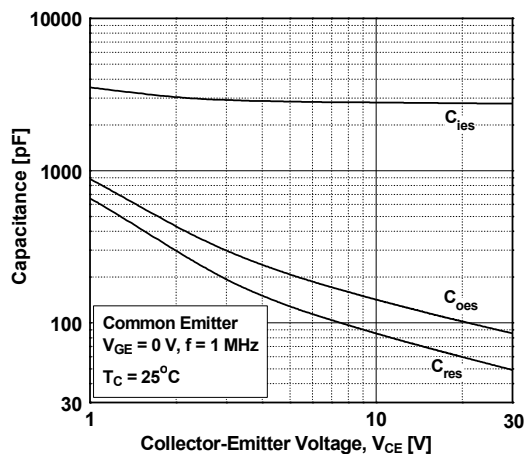


Figure 8. Gate charge Characteristics

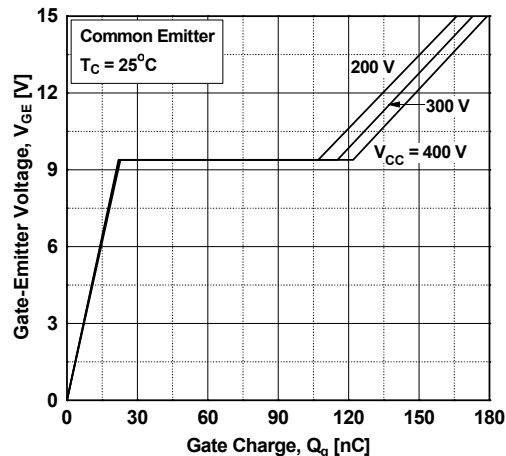


Figure 9. Turn-on Characteristics vs. Gate Resistance

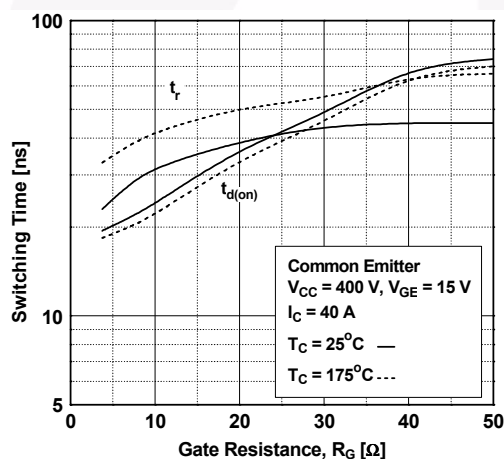


Figure 10. Turn-off Characteristics vs. Gate Resistance

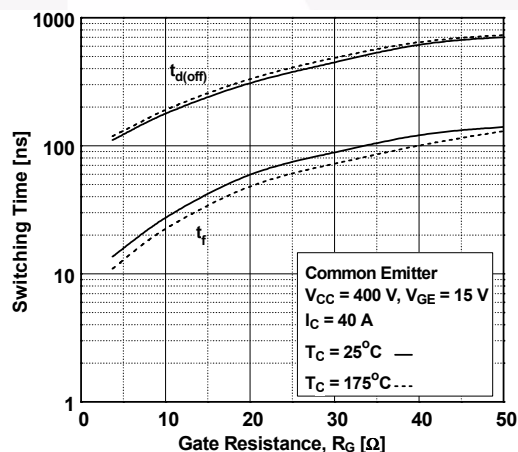


Figure 11. Switching Loss vs. Gate Resistance

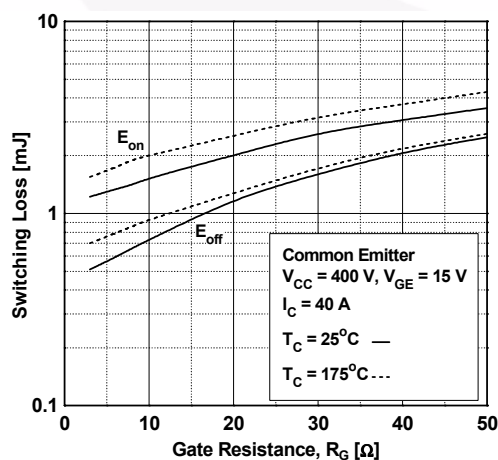
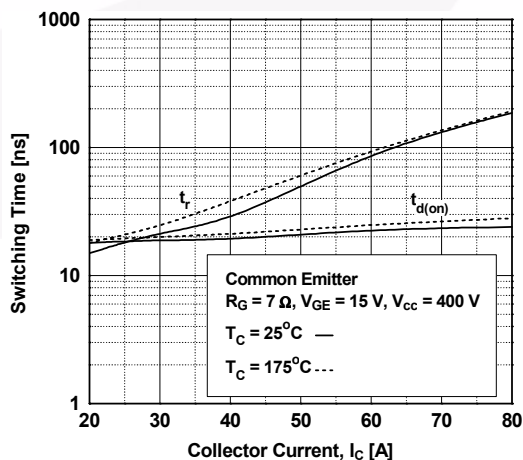


Figure 12. Turn-on Characteristics vs. Collector Current



Typical Performance Characteristics

Figure 13. Turn-off Characteristics vs. Collector Current

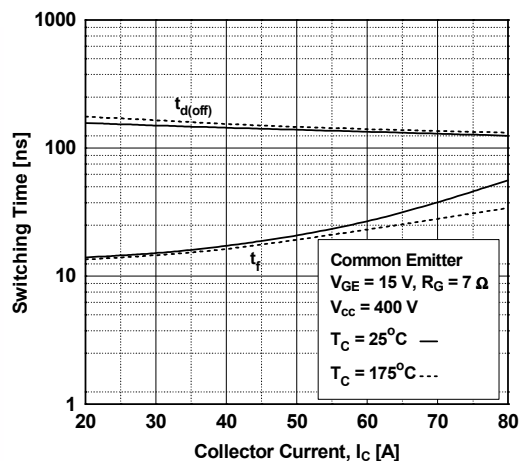


Figure 14. Switching Loss vs. Collector Current

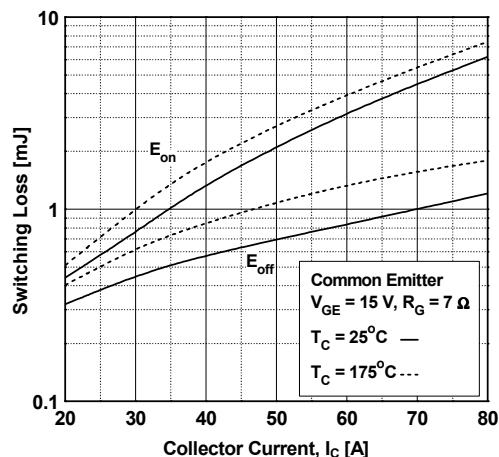


Figure 15. Load Current vs. Frequency

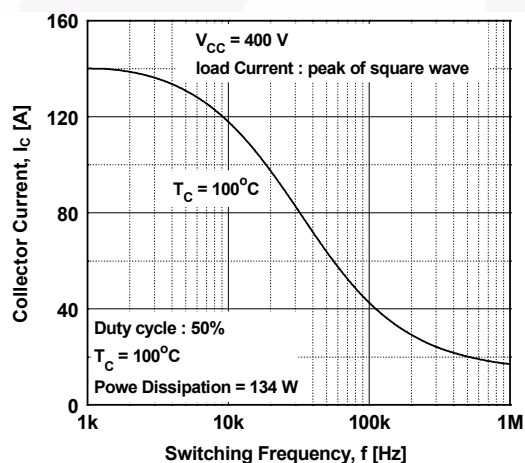


Figure 16. SOA Characteristics

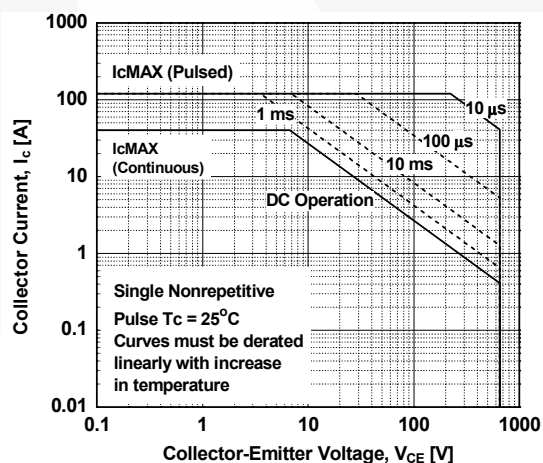


Figure 17. Forward Characteristics

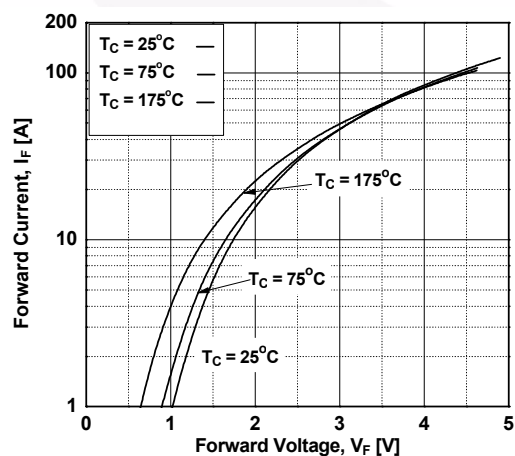
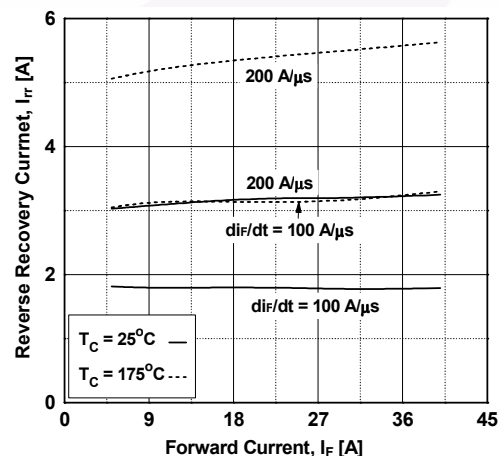


Figure 18. Reverse Recovery Current



Typical Performance Characteristics

Figure 19. Reverse Recovery Time

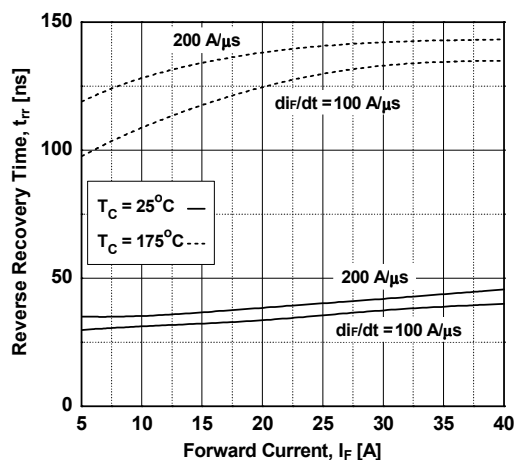


Figure 20. Stored Charge

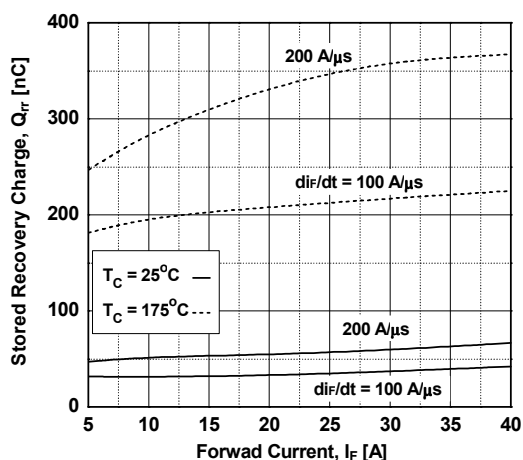


Figure 21. Transient Thermal Impedance of IGBT

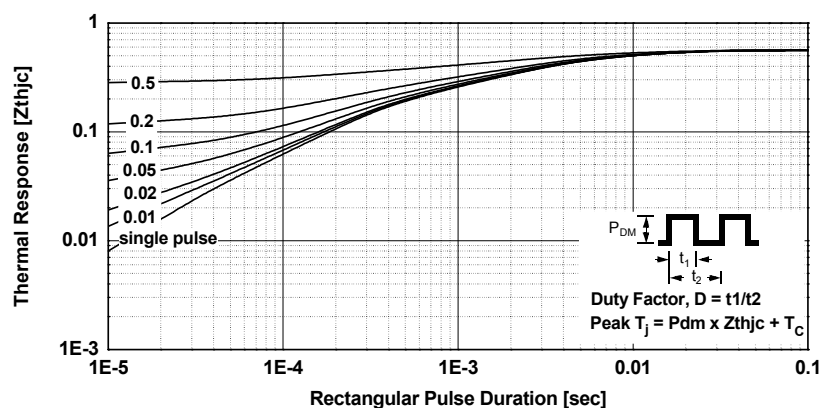
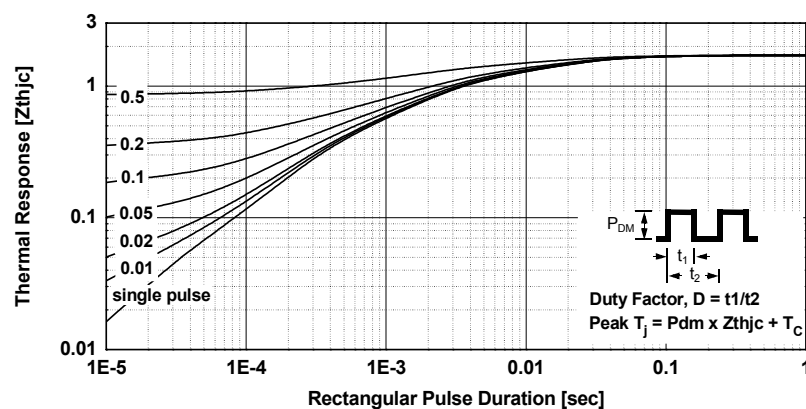
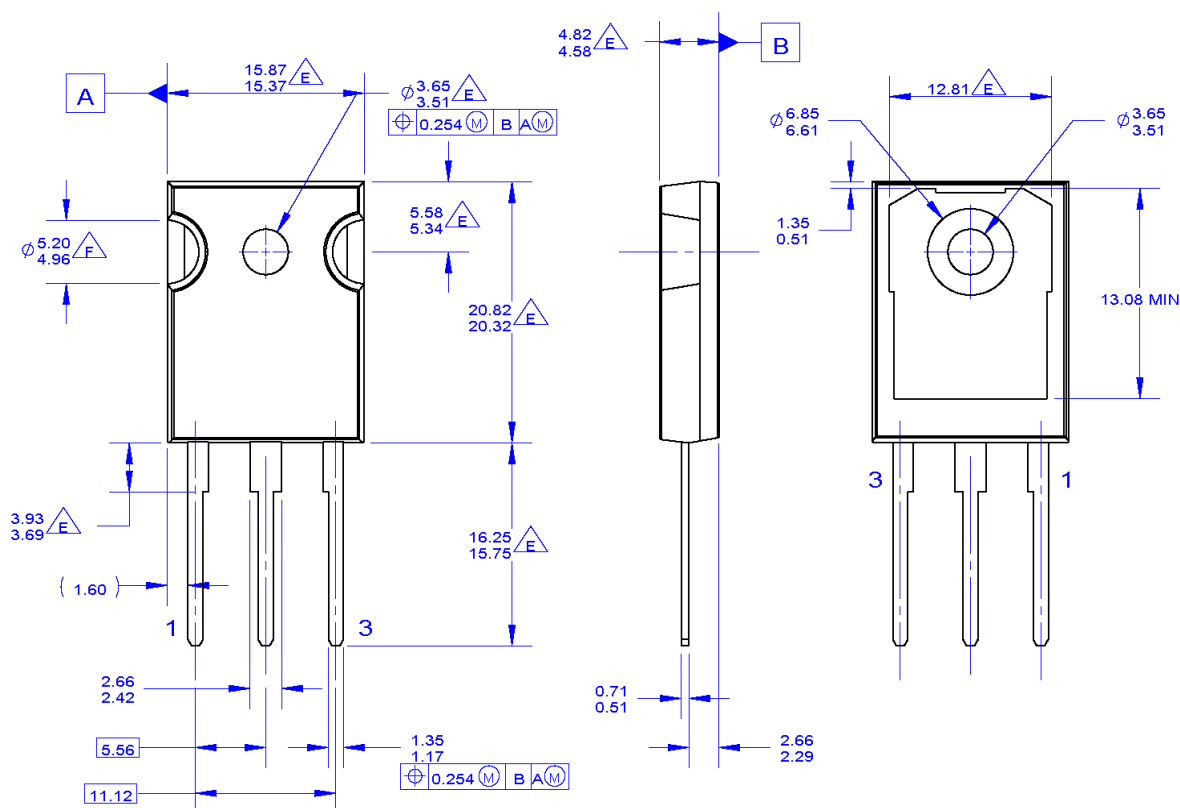


Figure 22. Transient Thermal Impedance of Diode



Mechanical Dimensions



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(E) DOES NOT COMPLY JEDEC STANDARD VALUE

(F) NOTCH MAY BE SQUARE

G. DRAWING FILENAME: MKT-TO247A03_REV03

Figure 23. TO-247, MOLDED, 3 LEAD, JEDEC VARIATION AB (Active)

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Dimensions in Millimeters



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Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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